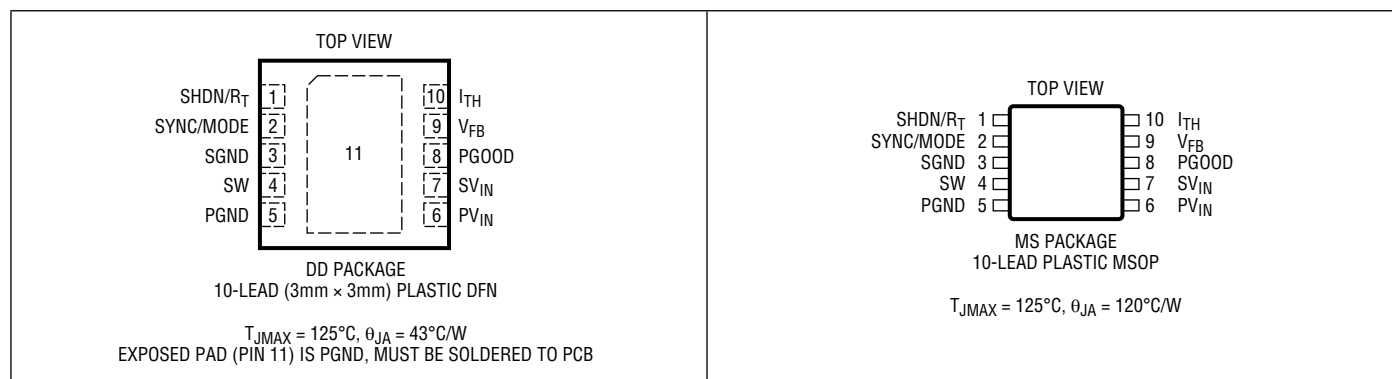


LTC3411A

ABSOLUTE MAXIMUM RATINGS (Note 1)

PV_{IN} , SV_{IN} Voltages	-0.3V to 6V	Operating Junction Temperature Range	
V_{FB} , I_{TH} , $SHDN/R_T$ Voltages	-0.3V to ($V_{IN} + 0.3V$)	(Notes 2, 5, 8)	-40°C to 125°C
SYNC/MODE Voltage	-0.3V to ($V_{IN} + 0.3V$)	Storage Temperature Range	-65°C to 125°C
SW Voltage	-0.3V to ($V_{IN} + 0.3V$)	Lead Temperature	
PGOOD Voltage	-0.3V to ($V_{IN} + 0.3V$)	(MS Package Soldering, 10 sec)	300°C

PIN CONFIGURATION



ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC3411AEDD#PBF	LTC3411AEDD#TRPBF	LAJMJ	10-Lead (3mm × 3mm) Plastic DFN	-40°C to 125°C
LTC3411AIDD#PBF	LTC3411AIDD#TRPBF	LAJMJ	10-Lead (3mm × 3mm) Plastic DFN	-40°C to 125°C
LTC3411AEMS#PBF	LTC3411AEMS#TRPBF	LTAJK	10-Lead Plastic MSOP	-40°C to 125°C
LTC3411AIMS#PBF	LTC3411AIMS#TRPBF	LTAJK	10-Lead Plastic MSOP	-40°C to 125°C

Contact the factory for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container.

[Tape and reel specifications](#). Some packages are available in 500 unit reels through designated sales channels with #TRMPBF suffix.

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating junction temperature range, otherwise specifications are at $T_A = 25^{\circ}C$, $V_{IN} = 3.6V$, $R_T = 125k$ unless otherwise specified. (Note 2)

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{IN}	Operating Voltage Range		●	2.5		5.5	V
I _{FB}	Feedback Pin Input Current	(Note 3)				±0.1	μA
V _{FB}	Feedback Voltage	(Note 3)	●	0.784	0.8	0.816	V
ΔV _{LINEREG}	Reference Voltage Line Regulation	V _{IN} = 2.5V to 5.5V			0.04	0.2	%/V
ΔV _{LOADREG}	Output Voltage Load Regulation	I _{TH} = 0.55V to 0.9V	●		0.02	0.2	%
g _{m(EA)}	Error Amplifier Transconductance	I _{TH} Pin Load = ±5μA (Note 3)			300		μS

Rev. E

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating junction temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$, $V_{IN} = 3.6\text{V}$, $R_T = 125\text{k}$ unless otherwise specified. (Note 2)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
I_S	Input DC Supply Current (Note 4)					
	Active Mode	$V_{\text{SYNC/MODE}} = 3.6\text{V}$, $V_{\text{FB}} = 0.75\text{V}$		330	450	μA
	Sleep Mode	$V_{\text{SYNC/MODE}} = 3.6\text{V}$, $V_{\text{FB}} = 0.84\text{V}$		40	60	μA
	Shutdown	$V_{\text{SHDN/RT}} = 3.6\text{V}$		0.1	1	μA
$V_{\text{SHDN/RT}}$	Shutdown Threshold High Active Oscillator Resistor			$V_{\text{IN}} - 0.6$ 125k	$V_{\text{IN}} - 0.4$ 1M	V Ω
f_{OSC}	Oscillator Frequency	$R_T = 125\text{k}$ (Note 7)	2.25	2.5	2.8 4	MHz MHz
f_{SYNC}	Synchronization Frequency	(Note 7)	0.4		4	MHz
I_{LIM}	Peak Switch Current Limit	$V_{\text{FB}} = 0.5\text{V}$	1.6	2.1	2.6	A
$R_{\text{DS(ON)}}$	Top Switch On-Resistance	MS Package		0.15	0.21	Ω
		DD Package (Note 6)		0.15		Ω
	Bottom Switch On-Resistance	MS Package		0.13	0.16	Ω
		DD Package (Note 6)		0.13		Ω
$I_{\text{SW(LKG)}}$	Switch Leakage Current	$V_{\text{IN}} = 5.5\text{V}$, $V_{\text{SHDN/RT}} = 5.5\text{V}$, $V_{\text{SW}} = 0\text{V}$ or 5.5V		0.01	1	μA
V_{UVLO}	Undervoltage Lockout Threshold	V_{IN} Ramping Down	1.8	2.1	2.4	V
PGOOD	Power Good Threshold	V_{FB} Ramping Up from 0.68V to 0.8V	-5	-7		%
		V_{FB} Ramping Down from 0.92V to 0.8V	5	7		%
	Power Bad Threshold	V_{FB} Ramping Down from 0.8V to 0.68V		-10	-12	%
		V_{FB} Ramping Up from 0.8V to 0.9V		10	12	%
R_{PGOOD}	Power Good Pull-Down On-Resistance			15	30	Ω
PGOOD Blanking		V_{FB} Step from 0V to 0.8V		40		μs
		V_{FB} Step from 0.8V to 0V		105		μs
$V_{\text{SYNC-MODE}}$	Pulse Skip	$V_{\text{IN}} = 2.5\text{V}$ to 5.5V			0.6	V
	Force Continuous	$V_{\text{IN}} = 2.5\text{V}$ to 5.5V	1.2		$V_{\text{IN}} - 1.1$	V
	Burst	$V_{\text{IN}} = 2.5\text{V}$ to 5.5V	$V_{\text{IN}} - 0.6$			V
$t_{\text{SOFT-START}}$		10% to 90% of Regulation	0.5	0.8	1.0	ms

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: The LTC3411A is tested under pulsed load conditions such that $T_J \approx T_A$. The LTC3411AE is guaranteed to meet performance specifications from 0°C to 85°C junction temperature. Specifications over the -40°C to 125°C operating junction temperature range are assured by design, characterization and correlation with statistical process controls. The LTC3411AI is guaranteed over the full -40°C to 125°C operating junction temperature range. The maximum ambient temperature consistent with these specifications is determined by specific operating conditions in conjunction with board layout, the rated package thermal resistance and other environmental factors.

Note 3: The LTC3411A is tested in a feedback loop which serves V_{FB} to the midpoint for the error amplifier ($V_{\text{ITH}} = 0.7\text{V}$).

Note 4: Dynamic supply current is higher due to the internal gate charge being delivered at the switching frequency.

Note 5: T_J is calculated from the ambient T_A and power dissipation P_D according to the following formulas:

$$\text{LTC3411AEDD: } T_J = T_A + (P_D \cdot 43^\circ\text{C/W})$$

$$\text{LTC3411AEMS: } T_J = T_A + (P_D \cdot 120^\circ\text{C/W})$$

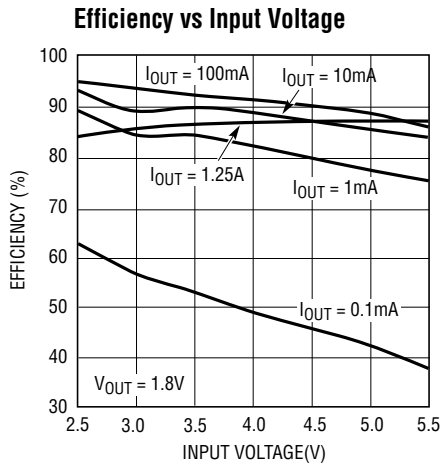
Note 6: For the DD package, switch on-resistance is sampled at wafer level measurements and assured by design, characterization and correlation with statistical process controls.

Note 7: 4MHz operation is guaranteed by design but not production tested and is subject to duty cycle limitations (see Applications Information).

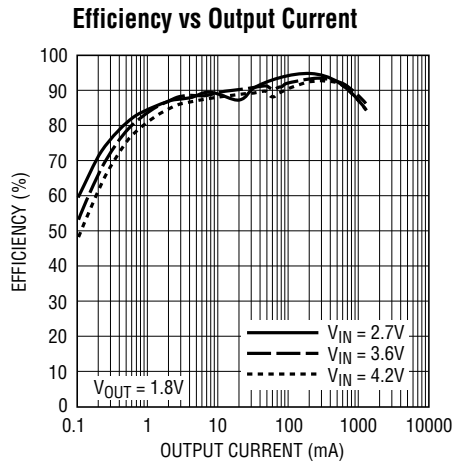
Note 8: This IC includes overtemperature protection that is intended to protect the device during momentary overload conditions. Junction temperature will exceed 125°C when overtemperature protection is active. Continuous operation above the specified maximum operating junction temperature may impair device reliability.

TYPICAL PERFORMANCE CHARACTERISTICS

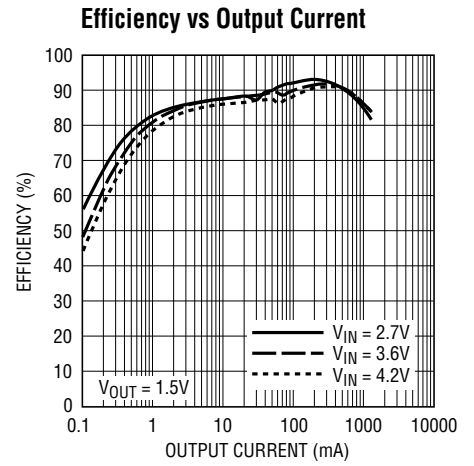
$T_A = 25^\circ\text{C}$, $V_{IN} = 3.6\text{V}$, $f_0 = 1\text{MHz}$, unless otherwise noted.



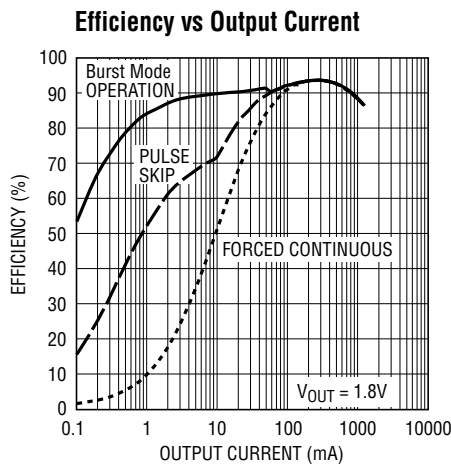
3411A G01



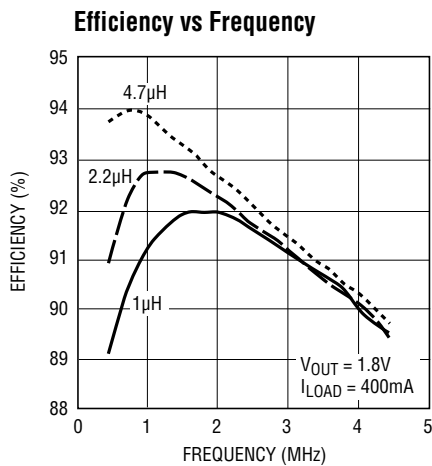
3411A G02



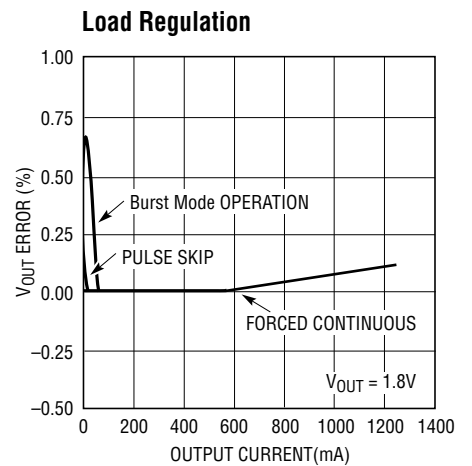
3411A G03



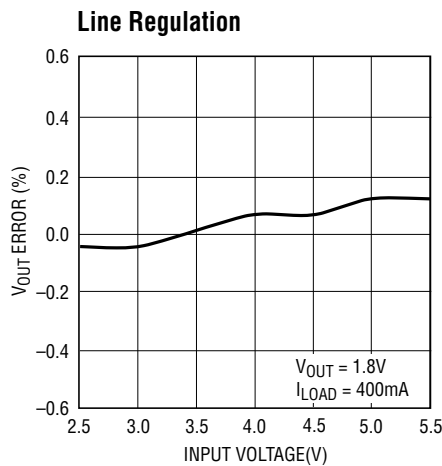
3411A G04



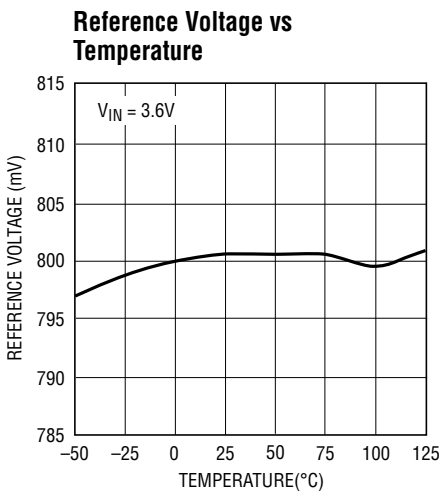
3411A G05



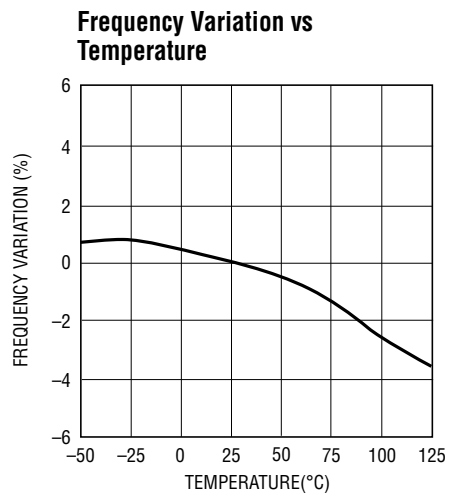
3411A G06



3411A G07

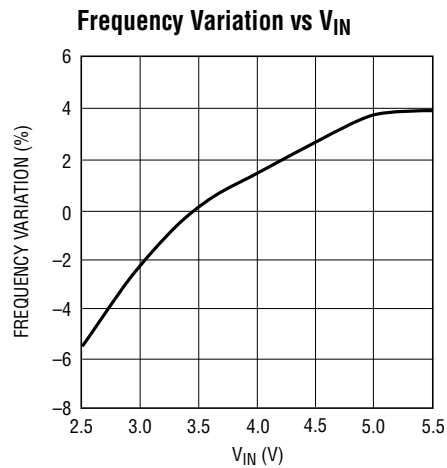


3411A G08

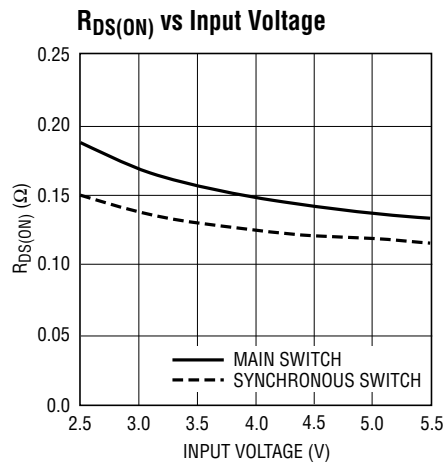


3411A G09

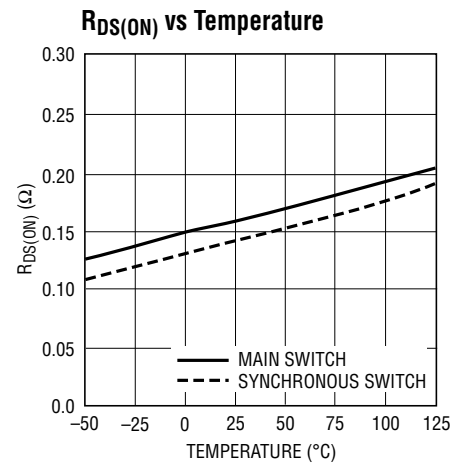
TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_{IN} = 3.6\text{V}$, $f_0 = 1\text{MHz}$, unless otherwise noted.



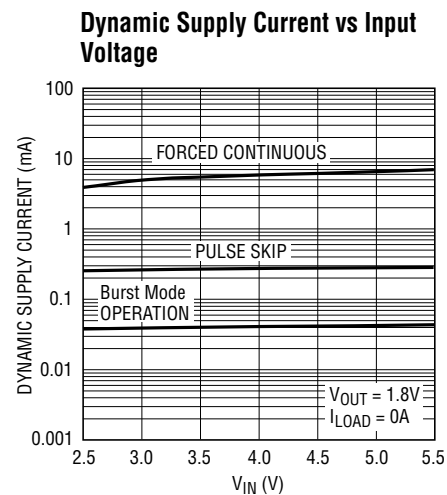
3411A G10



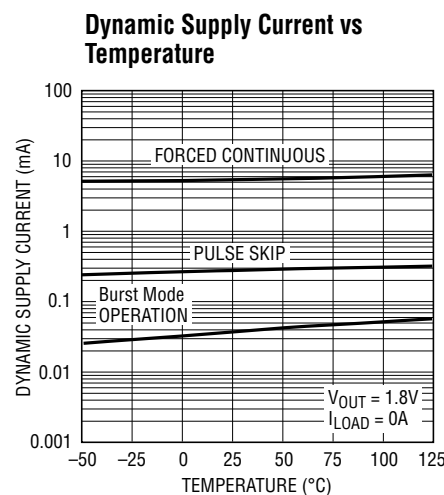
3411A G11



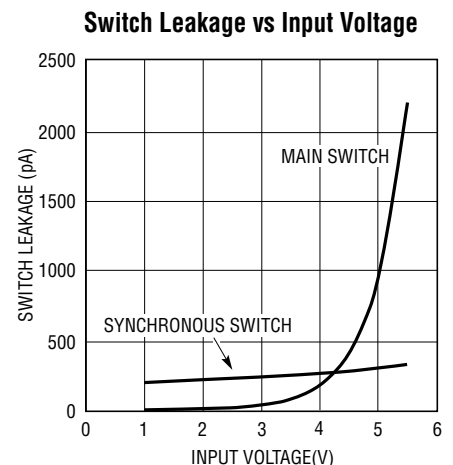
3411A G12



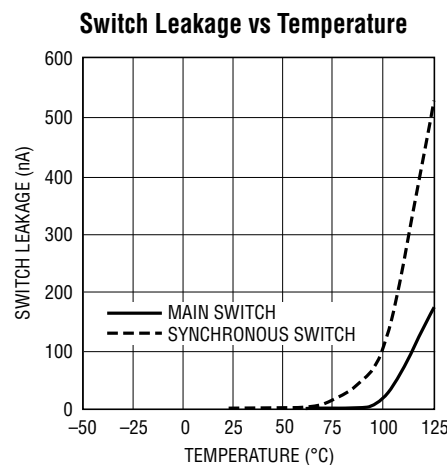
3411A G13



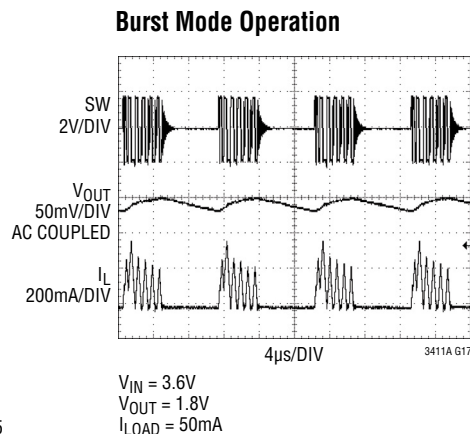
3411A G14



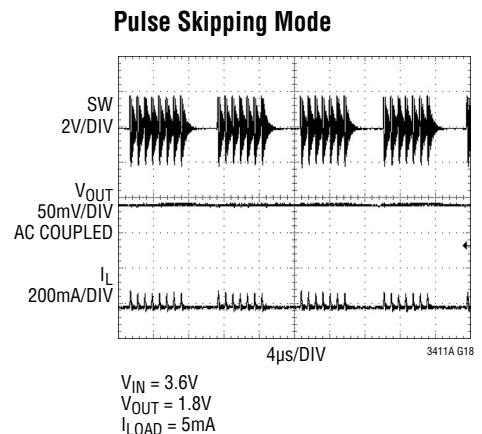
3411A G15



3411A G16



3411A G17

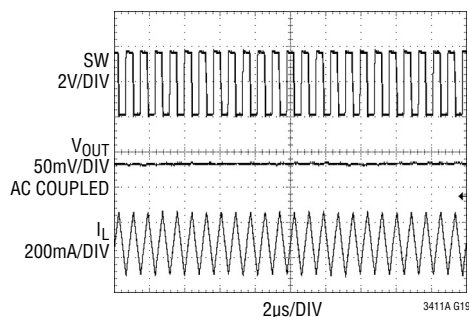


3411A G18

TYPICAL PERFORMANCE CHARACTERISTICS

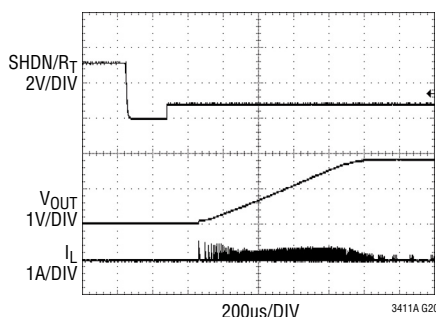
$T_A = 25^\circ\text{C}$, $V_{IN} = 3.6\text{V}$, $f_0 = 1\text{MHz}$, unless otherwise noted.

Forced Continuous Mode



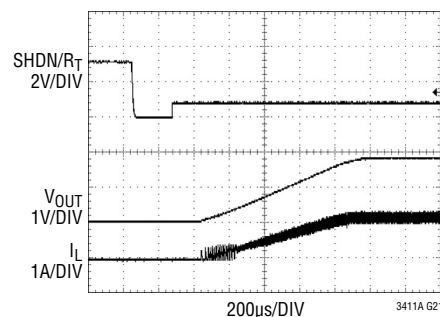
$V_{IN} = 3.6\text{V}$
 $V_{OUT} = 1.8\text{V}$
 $I_{LOAD} = 80\text{mA}$

Start-Up from Shutdown



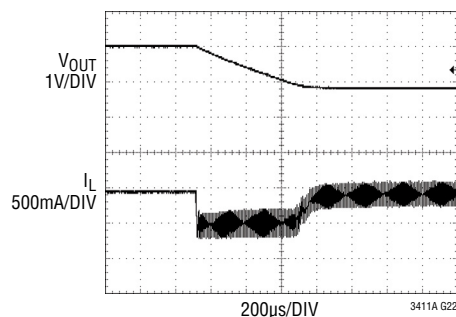
$V_{IN} = 3.6\text{V}$
 $V_{OUT} = 1.8\text{V}$
 $I_{LOAD} = 0\text{A}$

Start-Up from Shutdown



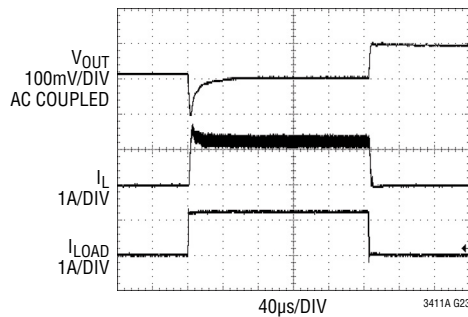
$V_{IN} = 3.6\text{V}$
 $V_{OUT} = 1.8\text{V}$
 $I_{LOAD} = 1.25\text{A}$

Start-Up from Shutdown with a Prebiased Output (Forced Continuous Mode)



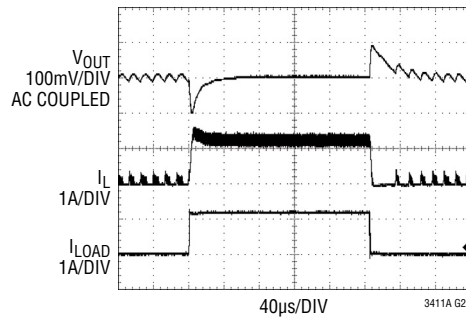
$V_{IN} = 3.6\text{V}$
 PREBIASED $V_{OUT} = 3\text{V}$, $V_{OUT} = 1.8\text{V}$
 $I_{LOAD} = 0\text{A}$

Load Step



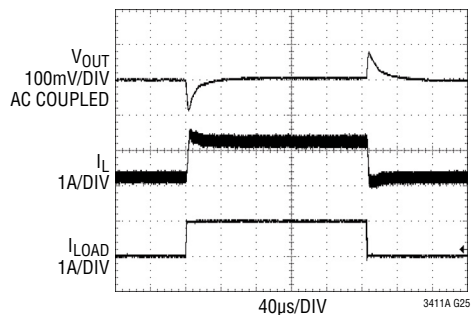
$V_{IN} = 3.6\text{V}$
 $V_{OUT} = 1.8\text{V}$
 $I_{LOAD} = 0\text{A}$ to 1.25A
 Burst Mode OPERATION

Load Step

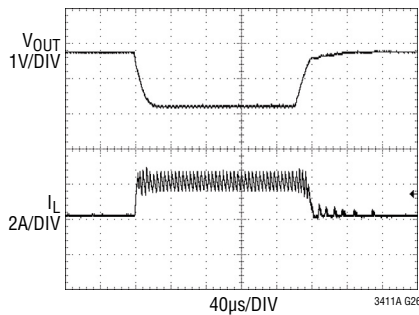


$V_{IN} = 3.6\text{V}$
 $V_{OUT} = 1.8\text{V}$
 $I_{LOAD} = 50\text{mA}$ to 1.25A
 Burst Mode OPERATION

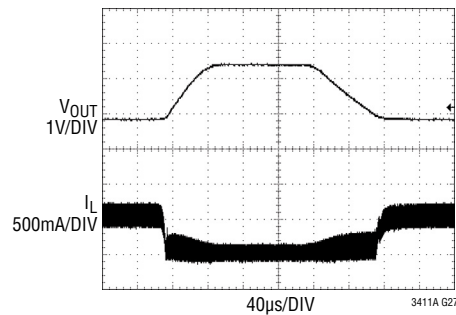
Load Step



$V_{IN} = 3.6\text{V}$
 $V_{OUT} = 1.8\text{V}$
 $I_{LOAD} = 250\text{mA}$ to 1.25A
 Burst Mode OPERATION

 V_{OUT} Short to Ground

$V_{IN} = 3.6\text{V}$
 $V_{OUT} = 1.8\text{V}$
 $I_{LOAD} = 0\text{A}$

 V_{OUT} Short to V_{IN} (Forced Continuous Mode)

$V_{IN} = 3.6\text{V}$
 $V_{OUT} = 1.8\text{V}$
 $I_{LOAD} = 0\text{A}$

PIN FUNCTIONS

SHDN/R_T (Pin 1): Combination Shutdown and Timing Resistor Pin. The oscillator frequency is programmed by connecting a resistor from this pin to ground. Forcing this pin to SV_{IN} causes the device to be shut down. In shutdown all functions are disabled.

SYNC/MODE (Pin 2): Combination Mode Selection and Oscillator Synchronization Pin. This pin controls the operation of the device. When tied to SV_{IN} or SGND, Burst Mode operation or pulse skipping mode is selected, respectively. If this pin is held at half of SV_{IN} , the forced continuous mode is selected. The oscillation frequency can be synchronized to an external oscillator applied to this pin. When synchronized to an external clock pulse skip mode is selected.

SGND (Pin 3): The Signal Ground Pin. All small-signal components and compensation components should be connected to this ground (see Board Layout Considerations).

SW (Pin 4): The Switch Node Connection to the Inductor. This pin swings from PV_{IN} to PGND.

PGND (Pin 5): Main Power Ground Pin. Connect to the (–) terminal of C_{OUT} , and (–) terminal of C_{IN} .

PV_{IN} (Pin 6): Main Supply Pin. Must be closely decoupled to PGND.

SV_{IN} (Pin 7): The Signal Power Pin. All active circuitry is powered from this pin. Must be closely decoupled to SGND. SV_{IN} must be greater than or equal to PV_{IN} .

PGOOD (Pin 8): The Power Good Pin. This common drain logic output is pulled to SGND when the output voltage is not within $\pm 7\%$ of regulation.

V_{FB} (Pin 9): Receives the feedback voltage from the external resistive divider across the output. Nominal voltage for this pin is 0.8V.

I_{TH} (Pin 10): Error Amplifier Compensation Point. The current comparator threshold increases with this control voltage. Nominal voltage range for this pin is 0.4V to 1.4V.

PGND (Exposed Pad Pin 11, DFN Package): Power Ground. Must be soldered to electrical ground on PCB.

PIN	NAME	DESCRIPTION	NOMINAL (V)			ABSOLUTE MAX (V)	
			MIN	TYP	MAX	MIN	MAX
1	SHDN/R _T	Shutdown/Timing Resistor	–0.3	0.8	SV_{IN}	–0.3	$SV_{IN} + 0.3$
2	SYNC/MODE	Mode Select/Synchronization Pin	0		SV_{IN}	–0.3	$SV_{IN} + 0.3$
3	SGND	Signal Ground		0			
4	SW	Switch Node	0		PV_{IN}	–0.3	$PV_{IN} + 0.3$
5	PGND	Main Power Ground		0			
6	PV _{IN}	Main Power Supply	–0.3		5.5	–0.3	$SV_{IN} + 0.3$
7	SV _{IN}	Signal Power Supply	2.5		5.5	–0.3	6
8	PGOOD	Power Good Pin	0		SV_{IN}	–0.3	6
9	V _{FB}	Output Feedback Pin	0	0.8	1.0	–0.3	$SV_{IN} + 0.3$
10	I _{TH}	Error Amplifier Compensation and Run Pin	0		1.5	–0.3	$SV_{IN} + 0.3$

For more information www.analog.com



OPERATION

The LTC3411A uses a constant frequency, current mode architecture. The operating frequency is determined by the value of the R_T resistor or can be synchronized to an external oscillator. To suit a variety of applications, the selectable MODE pin allows the user to trade-off noise for efficiency.

The output voltage is set by an external divider returned to the V_{FB} pin. An error amplifier compares the divided output voltage with the reference voltage of 0.8V and adjusts the peak inductor current accordingly. Overvoltage and undervoltage comparators will pull the PGOOD output low if the output voltage is not within $\pm 7\%$ of its regulated value. A tripping delay of 40 μ s and untripping delay of 105 μ s ensures PGOOD will not glitch due to transient spikes on V_{OUT} .

Main Control Loop

During normal operation, the top power switch (P-channel MOSFET) is turned on at the beginning of a clock cycle. Current flows through this switch into the inductor and the load, increasing until the peak inductor current reaches the limit set by the voltage on the I_{TH} pin. Then the top switch is turned off, the bottom switch is turned on, and the energy stored in the inductor forces the current to flow through the bottom switch and the inductor, out into the load until the next clock cycle.

The peak inductor current is controlled by the voltage on the I_{TH} pin, which is the output of the error amplifier. The output is developed by the error amplifier comparing the feedback voltage, V_{FB} , to the 0.8V reference voltage. When the load current increases, the output voltage and V_{FB} decrease slightly. This decrease in V_{FB} causes the error amplifier to increase the I_{TH} voltage until the average inductor current matches the new load current.

The main control loop is shut down by pulling the SHDN/ R_T pin to SV_{IN} , resetting the internal soft-start. Re-enabling the main control loop by releasing the SHDN/ R_T pin activates the internal soft-start, which slowly ramps the output voltage over approximately 0.8ms until it reaches regulation.

Low Current Operation

Three modes are available to control the operation of the LTC3411A at low currents. All three modes automatically switch from continuous operation to the selected mode when the load current is low.

To optimize efficiency, the Burst Mode operation can be selected. When the load is relatively light, the LTC3411A automatically switches into Burst Mode operation in which the PMOS switch operates intermittently based on load demand. By running cycles periodically, the switching losses which are dominated by the gate charge losses of the power MOSFETs are minimized. The main control loop is interrupted when the output voltage reaches the desired regulated value. The burst comparator trips when I_{TH} is below approximately 0.5V, shutting off the switch and reducing the power. The output capacitor and the inductor supply the power to the load until I_{TH} rises above approximately 0.5V, turning on the switch and the main control loop which starts another cycle.

For lower output voltage ripple at low currents, pulse skipping mode can be used. In this mode, the LTC3411A continues to switch at a constant frequency down to very low currents, where it will eventually begin skipping pulses.

Finally, in forced continuous mode, the inductor current is constantly cycled which creates a fixed output voltage ripple at all output current levels. This feature is desirable in telecommunications since the noise is at a constant frequency and is thus, easy to filter out. Another advantage of this mode is that the regulator is capable of both sourcing current into a load and sinking current from the output.

Dropout Operation

When the input supply voltage decreases toward the output voltage, the duty cycle increases to 100% which is the dropout condition. In dropout, the PMOS switch is turned on continuously with the output voltage being equal to the input voltage minus the voltage drop across the internal P-channel MOSFET and the inductor.

Low Supply Operation

The LTC3411A incorporates an undervoltage lockout circuit which shuts down the part when the input voltage drops below about 2.1V to prevent unstable operation.

APPLICATIONS INFORMATION

A general LTC3411A application circuit is shown in Figure 4. External component selection is driven by the load requirement, and begins with the selection of the inductor L1. Once L1 is chosen, C_{IN} and C_{OUT} can be selected.

Operating Frequency

Selection of the operating frequency is a trade-off between efficiency and component size. High frequency operation allows the use of smaller inductor and capacitor values. Operation at lower frequencies improves efficiency by reducing internal gate charge losses but requires larger inductance values and/or capacitance to maintain low output ripple voltage.

The operating frequency, f_O, of the LTC3411A is determined by an external resistor that is connected between the R_T pin and ground. The value of the resistor sets the ramp current that is used to charge and discharge an internal timing capacitor within the oscillator and can be calculated by using the following equation:

$$R_T = 5 \cdot 10^7 (f_O)^{-1.6508} \text{ (k}\Omega\text{)},$$

where f_O is in kHz, or can be selected using Figure 1.

The maximum usable operating frequency is limited by the minimum on-time and the duty cycle. This can be calculated as:

$$f_{O(\text{MAX})} \approx 6.67 \cdot \frac{V_{\text{OUT}}}{V_{\text{IN}(\text{MAX})}} \text{ (MHz)}$$

The minimum frequency is internally set at around 200kHz.

Inductor Selection

The operating frequency, f_O, has a direct effect on the inductor value, which in turn influences the inductor ripple current ΔI_L:

$$\Delta I_L = \frac{V_{\text{OUT}}}{f_O \cdot L} \cdot \left(1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}\right)$$

The inductor ripple current decreases with larger inductance or frequency, and increases with higher V_{IN} or V_{OUT}. Accepting larger values of ΔI_L allows the use of lower

inductances, but results in higher output ripple voltage, greater core loss and lower output capability.

A reasonable starting point for setting ripple current is ΔI_L = 0.4 • I_{OUT(MAX)}, where I_{OUT(MAX)} is 1.25A. The largest ripple current ΔI_L occurs at the maximum input voltage. To guarantee that the ripple current stays below a specified maximum, the inductor value should be chosen according to the following equation:

$$L = \frac{V_{\text{OUT}}}{f_O \cdot \Delta I_L} \cdot \left(1 - \frac{V_{\text{OUT}}}{V_{\text{IN}(\text{MAX})}}\right)$$

The inductor value will also have an effect on Burst Mode operation. The transition from low current operation begins when the peak inductor current falls below a level set by the burst clamp. Lower inductor values result in higher ripple current which causes this to occur at lower load currents. This causes a dip in efficiency in the upper range of low current operation. In Burst Mode operation,

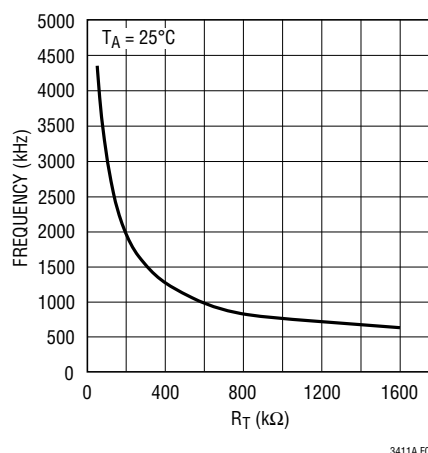


Figure 1. Frequency vs R_T

lower inductance values will cause the burst frequency to increase.

Inductor Core Selection

Different core materials and shapes will change the size/current and price/current relationship of an inductor. Toroid or shielded pot cores in ferrite or permalloy materials are small and don't radiate much energy, but generally cost more than powdered iron core inductors with similar electrical characteristics. The choice of which style

APPLICATIONS INFORMATION

inductor to use often depends more on the price vs size requirements and any radiated field/EMI requirements than on what the LTC3411A requires to operate. Table 1 shows some typical surface mount inductors that work well in LTC3411A applications.

Table 1. Representative Surface Mount Inductors

MANUFACTURER	PART NUMBER	VALUE	MAX DC CURRENT	DCR	HEIGHT
Toko	A914BYW-1R2M=P3: D52LC	1.2μH	2.15A	44mΩ	2mm
	A960AW-1R2M=P3: D518LC	1.2μH	1.8A	46mΩ	1.8mm
	DB3015C-1068AS-1R0N	1.0μH	2.1A	43mΩ	1.5mm
	DB3018C-1069AS-1R0N	1.0μH	2.1A	45mΩ	1.8mm
	DB3020C-1070AS-1R0N	1.0μH	2.1A	47mΩ	2mm
	A914BYW-2R2M-D52LC	2.2μH	2.05A	49mΩ	2mm
	A915AY-2R0M-D53LC	2.0μH	3.3A	22mΩ	3mm
Coilcraft	LPO1704-122ML	1.2μH	2.1A	80mΩ	1mm
	D01608C-222	2.2μH	2.3A	70mΩ	3mm
	LP01704-222M	2.2μH	2.4A	120mΩ	1mm
Sumida	CR32-1R0	1.0μH	2.1A	72mΩ	3mm
	CR5D11-1R0	1.0μH	2.2A	40mΩ	1.2mm
	CDRH3D14-1R2	1.2μH	2.2A	36mΩ	1.5mm
	CDRH4D18C/LD-1R1	1.1μH	2.1A	24mΩ	2mm
	CDRH4D28C/LD-1R0	1.0μH	3.0A	17.5mΩ	3mm
	CDRH4D28C-1R1	1.1μH	3.8A	22mΩ	3mm
	CDRH4D28-1R2	1.2μH	2.56A	23.6mΩ	3mm
	CDRH6D12-1R0	1.0μH	2.80A	37.5mΩ	1.5mm
	CDRH4D282R2	2.2μH	2.04A	23mΩ	3mm
	CDC5D232R2	2.2μH	2.16A	30mΩ	2.5mm
Taiyo Yuden	NPO3SB1R0M	1.0μH	2.6A	27mΩ	1.8mm
	N06DB2R2M	2.2μH	3.2A	29mΩ	3.2mm
	N05DB2R2M	2.2μH	2.9A	32mΩ	2.8mm
Murata	LQN6C2R2M04	2.2μH	3.2A	24mΩ	5mm
FDK	MIPW3226DORGM	0.9μH	1.4A	80mΩ	1mm

Catch Diode Selection

Although unnecessary in most applications, a small improvement in efficiency can be obtained in a few applications by including the optional diode D1 shown in Figure 4, which conducts when the synchronous switch is off. When using Burst Mode operation or pulse skip

mode, the synchronous switch is turned off at a low current and the remaining current will be carried by the optional diode. It is important to adequately specify the diode peak current and average power dissipation so as not to exceed the diode ratings. The main problem with Schottky diodes is that their parasitic capacitance reduces the efficiency, usually negating the possible benefits for LTC3411A circuits. Another problem that a Schottky diode can introduce is higher leakage current at high temperatures, which could reduce the low current efficiency.

Remember to keep lead lengths short and observe proper grounding (see Board Layout Considerations) to avoid ringing and increased dissipation when using a catch diode.

Input Capacitor (C_{IN}) Selection

In continuous mode, the input current of the converter is a square wave with a duty cycle of approximately V_{OUT}/V_{IN} . To prevent large voltage transients, a low equivalent series resistance (ESR) input capacitor sized for the maximum RMS current must be used. The maximum RMS capacitor current is given by:

$$I_{RMS} \approx I_{MAX} \frac{\sqrt{V_{OUT}(V_{IN} - V_{OUT})}}{V_{IN}}$$

where the maximum average output current I_{MAX} equals the peak current minus half the peak-to-peak ripple current, $I_{MAX} = I_{LIM} - \Delta I_L/2$.

This formula has a maximum at $V_{IN} = 2V_{OUT}$, where $I_{RMS} \approx I_{OUT}/2$. This simple worst case is commonly used to design because even significant deviations do not offer much relief. Note that capacitor manufacturer's ripple current ratings are often based on only 2000 hours lifetime. This makes it advisable to further derate the capacitor, or choose a capacitor rated at a higher temperature than required. Several capacitors may also be paralleled to meet the size or height requirements of the design. An additional 0.1μF to 1μF ceramic capacitor is also recommended on V_{IN} for high frequency decoupling, when not using an all ceramic capacitor solution.

APPLICATIONS INFORMATION

Output Capacitor (C_{OUT}) Selection

The selection of C_{OUT} is driven by the required ESR to minimize voltage ripple and load step transients. Typically, once the ESR requirement is satisfied, the capacitance is adequate for filtering. The output ripple (ΔV_{OUT}) is determined by:

$$\Delta V_{OUT} \approx \Delta I_L \left(\text{ESR} + \frac{1}{8f_0 C_{OUT}} \right)$$

where f_0 = operating frequency, C_{OUT} = output capacitance and ΔI_L = ripple current in the inductor. The output ripple is highest at maximum input voltage since ΔI_L increases with input voltage. With $\Delta I_L = 0.4 \cdot I_{OUT(MAX)}$ the output ripple will be less than 100mV at maximum V_{IN} , a minimum C_{OUT} value of 10 μ F and $f_0 = 1$ MHz with:

$$\text{ESR}_{C_{OUT}} < 150\text{m}\Omega$$

Once the ESR requirements for C_{OUT} have been met, the RMS current rating generally far exceeds the $I_{RIPPLE(P-P)}$ requirement, except for an all ceramic solution.

In surface mount applications, multiple capacitors may have to be paralleled to meet the capacitance, ESR or RMS current handling requirement of the application. Aluminum electrolytic, special polymer, ceramic and dry tantalum capacitors are all available in surface mount packages. The OS-CON semiconductor dielectric capacitor available from Sanyo has the lowest ESR(size) product of any aluminum electrolytic at a somewhat higher price. Special polymer capacitors, such as Sanyo POSCAP, offer very low ESR, but have a lower capacitance density than other types. Tantalum capacitors have the highest capacitance density, but it has a larger ESR and it is critical that the capacitors are surge tested for use in switching power supplies. An excellent choice is the AVX TPS series of surface mount tantalums, available in case heights ranging from 2mm to 4mm. Aluminum electrolytic capacitors have a significantly larger ESR, and is often used in extremely cost-sensitive applications provided that consideration is given to ripple current ratings and long term reliability. Ceramic capacitors have the lowest ESR and cost but also have the lowest capacitance density, a high voltage and temperature coefficient and exhibit audible piezoelectric effects. In addition, the high Q of ceramic capacitors along with trace inductance can lead to significant ringing. Other

capacitor types include the Panasonic specialty polymer (SP) capacitors.

In most cases, 0.1 μ F to 1 μ F of ceramic capacitors should also be placed close to the LTC3411A in parallel with the main capacitors for high frequency decoupling.

Ceramic Input and Output Capacitors

Higher value, lower cost ceramic capacitors are now becoming available in smaller case sizes. Their high ripple current, high voltage rating and low ESR make them ideal for switching regulator applications. Because the LTC3411A's control loop does not depend on the output capacitor's ESR for stable operation, ceramic capacitors can be used freely to achieve very low output ripple and small circuit size.

However, care must be taken when ceramic capacitors are used at the input and the output. When a ceramic capacitor is used at the input and the power is supplied by a wall adapter through long wires, a load step at the output can induce ringing at the input, V_{IN} . At best, this ringing can couple to the output and be mistaken as loop instability. At worst, a sudden inrush of current through the long wires can potentially cause a voltage spike at V_{IN} , large enough to damage the part.

When choosing the input and output ceramic capacitors, choose the X5R or X7R dielectric formulations. These dielectrics have the best temperature and voltage characteristics of all the ceramics for a given value and size.

Since the ESR of a ceramic capacitor is so low, the input and output capacitor must instead fulfill a charge storage requirement. During a load step, the output capacitor must instantaneously supply the current to support the load until the feedback loop raises the switch current enough to support the load. The time required for the feedback loop to respond is dependent on the compensation components and the output capacitor size. Typically, 3 to 4 cycles are required to respond to a load step, but only in the first cycle does the output drop linearly. The output droop, V_{DROOP} , is usually about 2 to 3 times the linear drop of the first cycle. Thus, a good place to start is with the output capacitor value of approximately:

APPLICATIONS INFORMATION

$$C_{OUT} \approx 2.5 \frac{\Delta I_{OUT}}{f_0 \cdot V_{DROOP}}$$

More capacitance may be required depending on the duty cycle and load step requirements.

In most applications, the input capacitor is merely required to supply high frequency bypassing, since the impedance to the supply is very low. A 10 μ F ceramic capacitor is usually enough for these conditions.

Setting the Output Voltage

The LTC3411A develops a 0.8V reference voltage between the feedback pin, V_{FB} , and the signal ground as shown in Figure 4. The output voltage is set by a resistive divider according to the following formula:

$$V_{OUT} \approx 0.8V \left(1 + \frac{R_2}{R_1} \right)$$

Keeping the current small (<5 μ A) in these resistors maximizes efficiency, but making them too small may allow stray capacitance to cause noise problems and reduce the phase margin of the error amp loop.

To improve the frequency response, a feed-forward capacitor C_F may also be used. Great care should be taken to route the V_{FB} line away from noise sources, such as the inductor or the SW line.

Shutdown and Soft-Start

The SHDN/ R_T pin is a dual purpose pin that sets the oscillator frequency and provides a means to shut down the LTC3411A. This pin can be interfaced with control logic in several ways, as shown in Figure 2 and Figure 3. In both configurations, Run = "0" shuts down the LTC3411A and Run = "1" activates the LTC3411A.

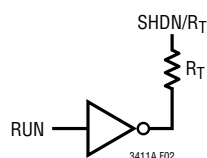


Figure 2. SHDN/ R_T Pin Activated with a Logic Input

Care must be taken when using Figure 3 to shut down the part in force continuous mode. The pull up resistor should be as small as the application would allow and the pull down transistor should be as small as possible to minimize its parasitic drain capacitance. If possible, always shut down the part while in pulse skipping mode or Burst Mode operation. Figure 4 shows an example of how to switch from force continuous mode to pulse skipping mode when RUN goes low. The parasitic drain capacitance of a large transistor coupled with a large pull up resistor results in large RC constants. As RUN goes low, the transistor drain charges up slowly, gradually decreasing the oscillator frequency of the part. This leads to large inductor current ripples translating into large output voltage ripples. In some cases, the output voltage could rise up to dangerous levels.

When activating the LTC3411A, an internal soft-start slowly ramps the output voltage up until regulation. Soft-start prevents surge currents from V_{IN} by gradually ramping the output voltage up during start-up. The output will ramp from zero to full scale over a time period of approximately 0.7ms. This prevents the LTC3411A from having to quickly charge the output capacitor and thus supplying an excessive amount of instantaneous current.

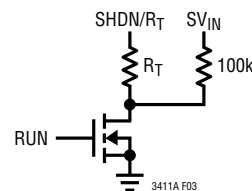


Figure 3. SHDN/ R_T Pin Activated with a Switch

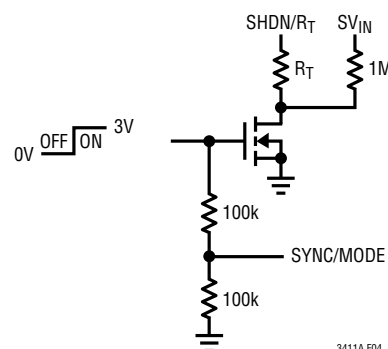


Figure 4. Automatic Mode Change Circuit

Rev. E

APPLICATIONS INFORMATION

error signal used by the regulator to return V_{OUT} to its steady-state value. During this recovery time, V_{OUT} can be monitored for overshoot or ringing that would indicate a stability problem.

The initial output voltage step may not be within the bandwidth of the feedback loop, so the standard second order overshoot/DC ratio cannot be used to determine phase margin. The gain of the loop increases with R and the bandwidth of the loop increases with decreasing C . If R is increased by the same factor that C is decreased, the zero frequency will be kept the same, thereby keeping the phase the same in the most critical frequency range of the feedback loop. In addition, a feedforward capacitor C_F can be added to improve the high frequency response, as shown in Figure 5. Capacitor C_F provides phase lead by creating a high frequency zero with $R2$ which improves the phase margin.

The output voltage settling behavior is related to the stability of the closed-loop system and will demonstrate the actual overall supply performance. For a detailed explanation of optimizing the compensation components, including a review of control loop theory, refer to ADI Application Note 76.

Although a buck regulator is capable of providing the full output current in dropout, it should be noted that as the input voltage V_{IN} drops toward V_{OUT} , the load step capability does decrease due to the decreasing voltage across the inductor. Applications that require large load step capability near dropout should use a different topology such as SEPIC, Zeta or single inductor, positive buck/boost.

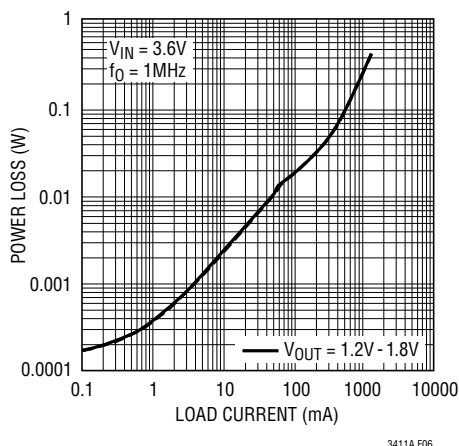


Figure 6. Power Loss vs Load Current

In some applications, a more severe transient can be caused by switching in loads with large ($>1\mu\text{F}$) input capacitors. The discharged input capacitors are effectively put in parallel with C_{OUT} , causing a rapid drop in V_{OUT} . No regulator can deliver enough current to prevent this problem, if the switch connecting the load has low resistance and is driven quickly. The solution is to limit the turn-on speed of the load switch driver. A Hot Swap™ controller is designed specifically for this purpose and usually incorporates current limiting, short-circuit protection, and soft-starting.

Efficiency Considerations

The percent efficiency of a switching regulator is equal to the output power divided by the input power times 100%. It is often useful to analyze individual losses to determine what is limiting the efficiency and which change would produce the most improvement. Percent efficiency can be expressed as:

$$\% \text{Efficiency} = 100\% - (L1 + L2 + L3 + \dots)$$

where $L1$, $L2$, etc. are the individual losses as a percentage of input power.

Although all dissipative elements in the circuit produce losses, four main sources usually account for most of the losses in LTC3411A circuits: 1) V_{IN} current, 2) switching losses, 3) I^2R losses, 4) other losses.

1) The V_{IN} current is the DC supply current given in the electrical characteristics which excludes MOSFET driver and control currents. V_{IN} current results in a small ($<0.1\%$) loss that increases with V_{IN} , even at no load.

2) The switching current is the sum of the MOSFET driver and control currents. The MOSFET driver current results from switching the gate capacitance of the power MOSFETs. Each time a MOSFET gate is switched from low to high to low again, a packet of charge dQ moves from V_{IN} to ground. The resulting dQ/dt is a current out of V_{IN} that is typically much larger than the DC bias current. In continuous mode, $I_{GATECHG} = f_0(QT + QB)$, where QT and QB are the gate charges of the internal top and bottom MOSFET switches. The gate charge losses are proportional to V_{IN} and thus their effects will be more pronounced at higher supply voltages.

APPLICATIONS INFORMATION

3) I^2R Losses are calculated from the DC resistances of the internal switches, R_{SW} , and external inductor, R_L . In continuous mode, the average output current flowing through inductor L is “chopped” between the internal top and bottom switches. Thus, the series resistance looking into the SW pin is a function of both top and bottom MOSFET $R_{DS(ON)}$ and the duty cycle (DC) as follows:

$$R_{SW} = (R_{DS(ON)TOP})(DC) + (R_{DS(ON)BOT})(1 - DC)$$

The $R_{DS(ON)}$ for both the top and bottom MOSFETs can be obtained from the Typical Performance Characteristics curves. Thus, to obtain I^2R losses:

$$I^2R \text{ losses} = I_{OUT}^2(R_{SW} + R_L)$$

4) Other “hidden” losses such as copper trace and internal battery resistances can account for additional efficiency degradations in portable systems. It is very important to include these “system” level losses in the design of a system. The internal battery and fuse resistance losses can be minimized by making sure that C_{IN} has adequate charge storage and very low ESR at the switching frequency. Other losses including diode conduction losses during dead-time and inductor core losses which generally account for less than 2% total additional loss.

Thermal Considerations

In a majority of applications, the LTC3411A does not dissipate much heat due to its high efficiency. However, in applications where the LTC3411A is running at high ambient temperature with low supply voltage and high duty cycles, such as in dropout, the heat dissipated may exceed the maximum junction temperature of the part. If the junction temperature reaches approximately 150°C, both power switches will be turned off and the SW node will become high impedance.

To avoid the LTC3411A from exceeding the maximum junction temperature, the user will need to do some thermal analysis. The goal of the thermal analysis is to determine whether the power dissipated exceeds the maximum junction temperature of the part. The temperature rise is given by:

$$T_{RISE} = P_D \cdot \theta_{JA}$$

where P_D is the power dissipated by the regulator and θ_{JA} is the thermal resistance from the junction of the die to the ambient temperature.

The junction temperature, T_J , is given by:

$$T_J = T_{RISE} + T_{AMBIENT}$$

As an example, consider the case when the LTC3411A is in dropout at an input voltage of 3.3V with a load current of 1A. From the Typical Performance Characteristics graph of Switch Resistance, the $R_{DS(ON)}$ resistance of the P-channel switch is 0.15Ω. Therefore, power dissipated by the part is:

$$P_D = I^2 \cdot R_{DS(ON)} = 150\text{mW}$$

The MS10 package junction-to-ambient thermal resistance, θ_{JA} , will be in the range of 100°C/W to 120°C/W. Therefore, the junction temperature of the regulator operating in a 70°C ambient temperature is approximately:

$$T_J = 0.15 \cdot 120 + 70 = 88^\circ\text{C}$$

Remembering that the above junction temperature is obtained from an $R_{DS(ON)}$ at 25°C, we might recalculate the junction temperature based on a higher $R_{DS(ON)}$ since it increases with temperature. However, we can safely assume that the actual junction temperature will not exceed the absolute maximum junction temperature of 125°C.

Design Example

As a design example, consider using the LTC3411A in a portable application with a Li-Ion battery. The battery provides a $V_{IN} = 2.5\text{V}$ to 4.2V. The load requires a maximum of 1.25A in active mode and 10mA in standby mode. The output voltage is $V_{OUT} = 2.5\text{V}$. Since the load still needs power in standby, Burst Mode operation is selected for good low load efficiency.

First, calculate the timing resistor for 1MHz operation:

$$R_T = 5 \cdot 10^7 (10^3)^{-1.6508} = 557.9\text{k}$$

Use a standard value of 549k. Next, calculate the inductor value for about 40% ripple current at maximum V_{IN} :

$$L = \frac{2.5\text{V}}{1\text{MHz} \cdot 500\text{mA}} \cdot \left(1 - \frac{2.5\text{V}}{4.2\text{V}}\right) = 2\mu\text{H}$$

Choosing the closest standard inductor value from a vendor of 2.2μH, results in a maximum ripple current of:

$$\Delta I_L = \frac{2.5\text{V}}{1\text{MHz} \cdot 2.2\mu\text{H}} \cdot \left(1 - \frac{2.5\text{V}}{4.2\text{V}}\right) = 460\text{mA}$$

APPLICATIONS INFORMATION

For cost reasons, a ceramic capacitor will be used. C_{OUT} selection is then based on load step droop instead of ESR requirements. For a 5% output droop:

$$C_{OUT} \approx 2.5 \frac{1.25A}{1MHz \cdot (5\% \cdot 2.5V)} = 25\mu F$$

The closest standard value is 22 μ F. Since the output impedance of a Li-Ion battery is very low, C_{IN} is typically 10 μ F. In noisy environments, decoupling SV_{IN} from PV_{IN} with an R6/C8 filter of 1 Ω /0.1 μ F may help, but is typically not needed.

The output voltage can now be programmed by choosing the values of R1 and R2. To maintain high efficiency, the current in these resistors should be kept small. Choosing 2 μ A with the 0.8V feedback voltage makes R1~400k. A close standard 1% resistor value is 412k. Then R2 is 887k.

The compensation should be optimized for these components by examining the load step response but a good place to start for the LTC3411A is with a 12.1k Ω and 680pF filter. The output capacitor may need to be increased depending on the actual undershoot during a load step.

The PGOOD pin is a common drain output and requires a pull-up resistor. A 100k resistor is used for adequate speed.

The circuit on page 1 of this data sheet shows the complete schematic for this design example.

Board Layout Considerations

When laying out the printed circuit board, the following checklist should be used to ensure proper operation of

the LTC3411A. These items are also illustrated graphically in the layout diagram of Figure 7. Check the following in your layout:

1. Does the capacitor C_{IN} connect to the power V_{IN} (Pin 6) and power GND (Pin 5) as close as possible? This capacitor provides the AC current to the internal power MOSFETs and their drivers.
2. Are the C_{OUT} and L1 closely connected? The (–) plate of C_{OUT} returns current to PGND and the (–) plate of C_{IN} .
3. The resistor divider, R1 and R2, must be connected between the (+) plate of C_{OUT} and a ground line terminated near SGND (Pin 3). The feedback signal V_{FB} should be routed away from noisy components and traces, such as the SW line (Pin 4), and its trace should be minimized.
4. Keep sensitive components away from the SW pin. The input capacitor C_{IN} , the compensation capacitor C_C and C_{ITH} and all the resistors R1, R2, R_T , and R_C should be routed away from the SW trace and the inductor L1. The SW pin pad should be kept as small as possible.
5. A ground plane is preferred, but if not available, keep the signal and power grounds segregated with small signal components returning to the SGND pin at one point which is then connected to the PGND pin.
6. Flood all unused areas on all layers with copper. Flooding with copper will reduce the temperature rise of power components. These copper areas should be connected to one of the input supplies: PV_{IN} , PGND, SV_{IN} or SGND.

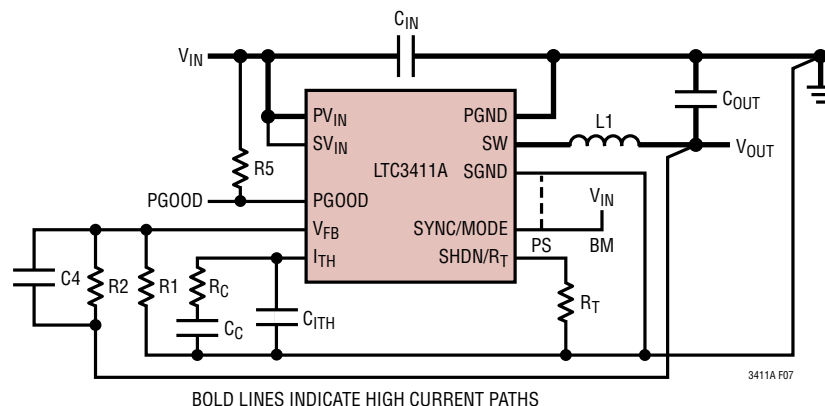
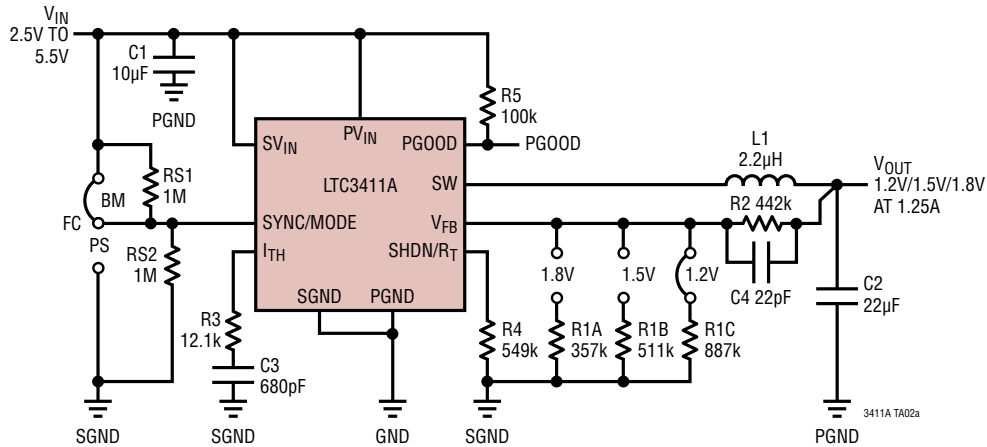


Figure 7. LTC3411A Layout Diagram (See Board Layout Checklist)

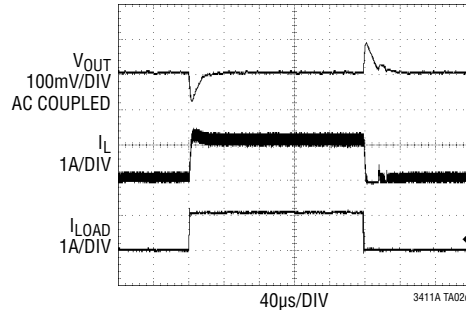
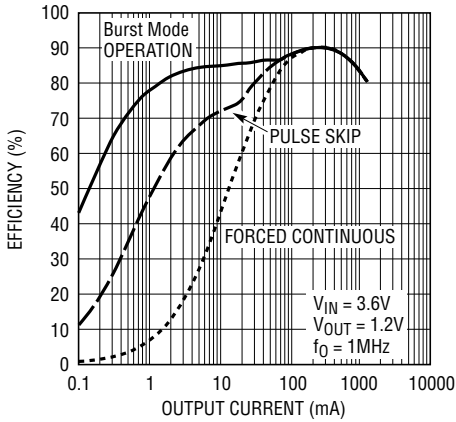
TYPICAL APPLICATIONS

General Purpose Buck Regulator Using Ceramic Capacitors

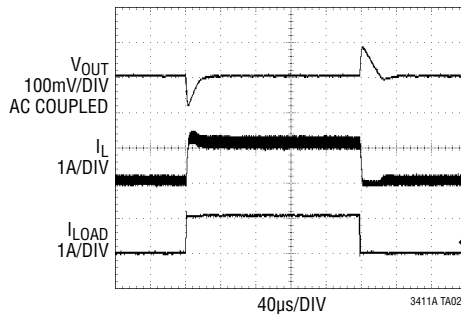


NOTE: IN DROPOUT, THE OUTPUT TRACKS THE INPUT VOLTAGE
 C1, C2: TAIYO YUDEN JMK325BJ226MM
 L1: TOKO A914BYW-2R2M (D52LC SERIES)

Efficiency vs Output Current



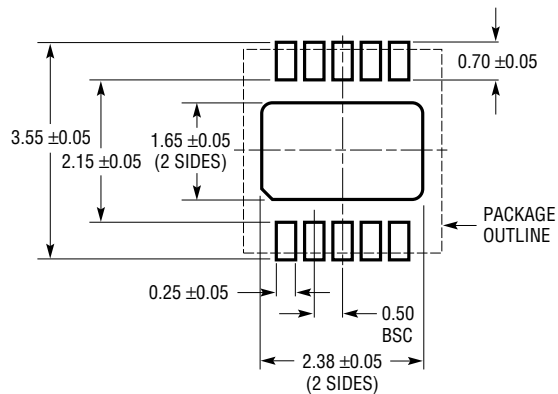
$V_{IN} = 3.6V$
 $V_{OUT} = 1.2V$
 $I_{LOAD} = 100mA$ TO $1.25A$
 Burst Mode OPERATION



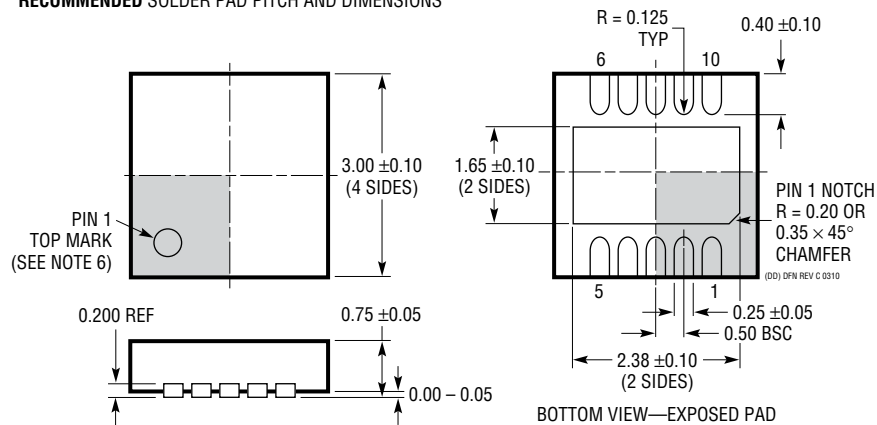
$V_{IN} = 3.6V$
 $V_{OUT} = 1.8V$
 $I_{LOAD} = 100mA$ TO $1.25A$
 PULSE SKIPPING MODE

PACKAGE DESCRIPTION

DD Package 10-Lead Plastic DFN (3mm × 3mm) (Reference LTC DWG # 05-08-1699 Rev C)



RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS

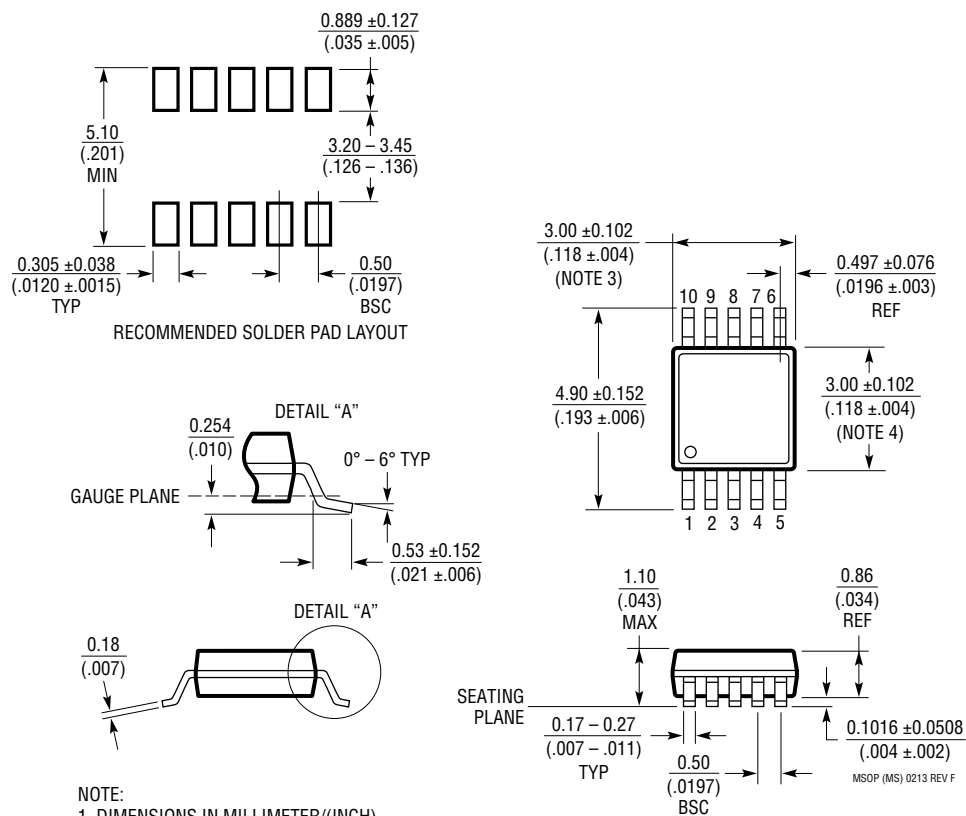


NOTE:

1. DRAWING TO BE MADE A JEDEC PACKAGE OUTLINE M0-229 VARIATION OF (WEED-2). CHECK THE LTC WEBSITE DATA SHEET FOR CURRENT STATUS OF VARIATION ASSIGNMENT
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

PACKAGE DESCRIPTION

MS Package
10-Lead Plastic MSOP
 (Reference LTC DWG # 05-08-1661 Rev F)



NOTE:

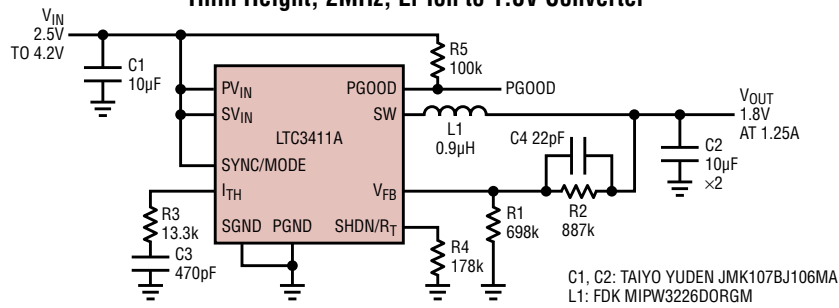
1. DIMENSIONS IN MILLIMETER/(INCH)
2. DRAWING NOT TO SCALE
3. DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX

REVISION HISTORY (Revision history begins at Rev B)

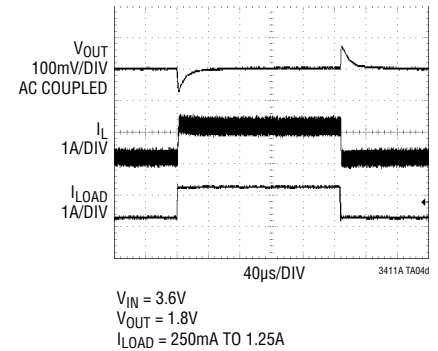
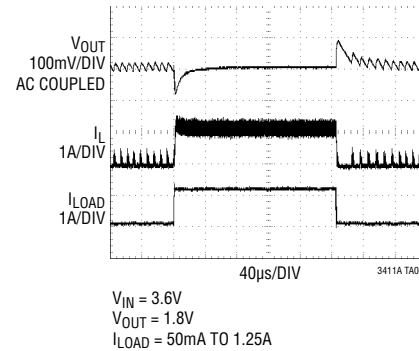
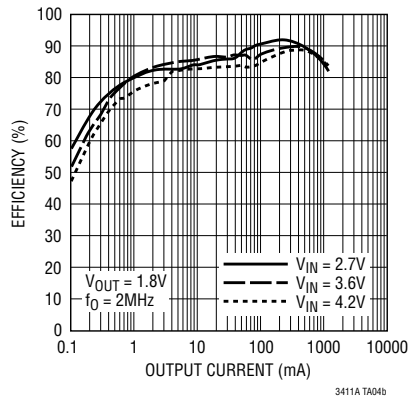
REV	DATE	DESCRIPTION	PAGE NUMBER
B	4/10	Remove θ_{JC} from Pin Configuration Section	2
		Update Minimum for $V_{SYNC/MODE}$ in Electrical Characteristics Update Note 2	3
		Update Pin 11 Description in Pin Functions	3
			7
C	10/13	Changed parameters and limits on $V_{SYNC-MODE}$ test	3
D	6/14	Modified ABS Max PGOOD Voltage	2
		Specified MS Package for Lead Temperature ABS Max	2
E	9/19	Changed Top Switch $R_{DS(ON)}$ from 0.18 Ω to 0.21 Ω Max in the Electrical Characteristics Table	3

TYPICAL APPLICATION

1mm Height, 2MHz, Li-Ion to 1.8V Converter



Efficiency vs Output Current



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC3406A/LTC3406AB	600mA (I _{OUT}), 1.5MHz Synchronous Step-Down DC/DC Converters	96% Efficiency, V _{IN} : 2.5V to 5.5V, V _{OUT(MIN)} = 0.6V, I _Q = 20µA, I _{SD} < 1µA, ThinSOT™
LTC3407A/LTC3407A-2	Dual 600mA/800mA (I _{OUT}), 1.5MHz/2.25MHz Synchronous Step-Down DC/DC Converters	95% Efficiency, V _{IN} : 2.5V to 5.5V, V _{OUT(MIN)} = 0.6V, I _Q = 40µA, I _{SD} < 1µA, MS10E, DFN
LTC3410/LTC3410B	300mA (I _{OUT}), 2.25MHz Synchronous Step-Down DC/DC Converters	95% Efficiency, V _{IN} : 2.5V to 5.5V, V _{OUT(MIN)} = 0.8V, I _Q = 26µA, I _{SD} < 1µA, SC70
LTC3411	1.25A (I _{OUT}), 4MHz Synchronous Step-Down DC/DC Converter	96% Efficiency, V _{IN} : 2.6V to 5.5V, V _{OUT(MIN)} = 0.8V, I _Q = 60µA, I _{SD} < 1µA, MS10, 3mm × 3mm DFN
LTC3412A	2.5A (I _{OUT}), 4MHz Synchronous Step-Down DC/DC Converter	96% Efficiency, V _{IN} : 2.6V to 5.5V, V _{OUT(MIN)} = 0.8V, I _Q = 62µA, I _{SD} < 1µA, TSSOP16E, 4mm × 4mm QFN
LTC3531/LTC3531-3 LTC3531-3.3	200mA (I _{OUT}), 1.5MHz Synchronous Buck-Boost DC/DC Converters	95% Efficiency, V _{IN} : 1.8V to 5.5V, V _{OUT(MIN)} = 2V to 5V, I _Q = 16µA, I _{SD} < 1µA, ThinSOT, DFN
LTC3532	500mA (I _{OUT}), 2MHz Synchronous Buck-Boost DC/DC Converter	95% Efficiency, V _{IN} : 2.4V to 5.5V, V _{OUT(MIN)} = 2.4V to 5.25V, I _Q = 35µA, I _{SD} < 1µA, MS10, DFN
LTC3542	500mA (I _{OUT}), 2.25MHz Synchronous Step-Down DC/DC Converter	95% Efficiency, V _{IN} : 2.5V to 5.5V, V _{OUT(MIN)} = 0.6V, I _Q = 26µA, I _{SD} < 1µA, 2mm × 2mm DFN
LTC3544/LTC3544B	Quad 300mA + 2 × 200mA + 100mA, 2.25MHz Synchronous Step-Down DC/DC Converter	95% Efficiency, V _{IN} : 2.5V to 5.5V, V _{OUT(MIN)} = 0.8V, I _Q = 70µA, I _{SD} < 1µA, 3mm × 3mm QFN
LTC3547/LTC3547B	Dual 300mA, 2.25MHz Synchronous Step-Down DC/DC Converters	96% Efficiency, V _{IN} : 2.5V to 5.5V, V _{OUT(MIN)} = 0.6V, I _Q = 40µA, I _{SD} < 1µA, 2mm × 3mm DFN
LTC3548/LTC3548-1 LTC3548-2	Dual 400mA/800mA, (I _{OUT}), 2.25MHz Synchronous Step-Down DC/DC Converters	95% Efficiency, V _{IN} : 2.5V to 5.5V, V _{OUT(MIN)} = 0.6V, I _Q = 40µA, I _{SD} < 1µA, MS10E, DFN
LTC3560	800mA (I _{OUT}), 2.25MHz Synchronous Step-Down DC/DC Converter	95% Efficiency, V _{IN} : 2.5V to 5.5V, V _{OUT(MIN)} = 0.6V, I _Q = 16µA, I _{SD} < 1µA, ThinSOT

Rev. E